Agilent MSA-0670 Cascadable Silicon Bipolar MMIC Amplifier

Data Sheet

Features

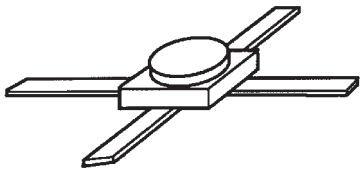
- **Cascadable 50 Ω Gain Block**
- **Low Operating Voltage:** 3.5 V Typical V_d
- **3 dB Bandwidth:** DC to 1.0 GHz
- **High Gain:** 19.5 dB Typical at 0.5 GHz
- **Low Noise Figure:** 2.8 dB Typical at 0.5 GHz
- **Hermetic Gold-ceramic Microstrip Package**

Description

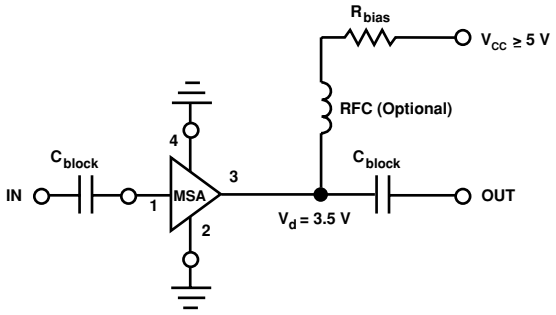
The MSA-0670 is a high performance silicon bipolar Monolithic Microwave Integrated Circuit (MMIC) housed in a hermetic, high reliability package. This MMIC is designed for use as a general purpose 50 Ω gain block. Typical applications include narrow and broad band IF and RF amplifiers in industrial and military applications.

The MSA-series is fabricated using Agilent's 10 GHz f_T, 25 GHz f_{MAX}, silicon bipolar MMIC process which uses nitride self-alignment, ion implantation, and gold metallization to achieve excellent performance, uniformity and reliability. The use of an external bias resistor for temperature and current stability also allows bias flexibility.

70 mil Package



Typical Biasing Configuration



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MSA-0670 Absolute Maximum Ratings

Parameter	Absolute Maximum[1]
Device Current	50 mA
Power Dissipation[2,3]	200 mW
RF Input Power	+13 dBm
Junction Temperature	200°C
Storage Temperature	–65 to 200°C

Thermal Resistance[2,4]:
θ_{jc} = 130°C/W

Notes:
1. Permanent damage may occur if any of these limits are exceeded.
2. T_{CASE} = 25°C.
3. Derate at 7.7 mW/°C for T_C > 174°C.
4. The small spot size of this technique results in a higher, though more accurate determination of θ_{jc} than do alternate methods.

Electrical Specifications[1], T_A = 25°C

Symbol	Parameters and Test Conditions: I_d = 16 mA, Z_O = 50 Ω		Units	Min.	Typ.	Max.
G_P	Power Gain ($\|S_{21}\|^2$)	f = 0.1 GHz	dB	19.0	20.5	22.0
ΔG_P	Gain Flatness	f = 0.1 to 0.6 GHz	dB		±0.7	±1.0
$f_{3\ dB}$	3 dB Bandwidth		GHz		1.0	
VSWR	Input VSWR	f = 0.1 to 1.5 GHz			1.9:1	
	Output VSWR	f = 0.1 to 1.5 GHz			1.8:1	
NF	50 Ω Noise Figure	f = 0.5 GHz	dB		2.8	4.0
$P_{1\ dB}$	Output Power at 1 dB Gain Compression	f = 0.5 GHz	dBm		2.0	
IP_3	Third Order Intercept Point	f = 0.5 GHz	dBm		14.5	
t_D	Group Delay	f = 0.5 GHz	psec		200	
V_d	Device Voltage		V	3.1	3.5	3.9
dV/dT	Device Voltage Temperature Coefficient		mV/°C		–8.0	

Note:
1. The recommended operating current range for this device is 12 to 30 mA. Typical performance as a function of current is on the following page.

MSA-0670 Typical Scattering Parameters (Z_O = 50 Ω, T_A = 25°C, I_d = 16 mA)

Freq. GHz	S_{11}		S_{21}			S_{12}			S_{22}		k
	Mag	Ang	dB	Mag	Ang	dB	Mag	Ang	Mag	Ang	
0.1	.05	–147	20.5	10.62	172	–23.3	.068	4	.05	–69	1.05
0.2	.07	–134	20.4	10.41	164	–23.0	.070	8	.09	–92	1.04
0.3	.09	–126	20.1	10.16	156	–22.6	.074	12	.13	–104	1.02
0.4	.11	–123	19.9	9.85	148	–22.4	.076	14	.16	–113	1.00
0.5	.13	–123	19.6	9.50	141	–22.0	.079	26	.20	–121	0.99
0.6	.15	–123	19.2	9.09	135	–21.3	.082	18	.22	–128	0.97
0.8	.19	–126	17.4	8.28	122	–20.7	.093	22	.25	–141	0.94
1.0	.24	–129	16.5	7.46	110	–19.8	.103	22	.27	–154	0.92
1.5	.31	–141	15.2	5.76	87	–18.2	.124	23	.27	–176	0.91
2.0	.38	–157	13.0	4.47	68	–17.2	.138	19	.24	166	0.94
2.5	.42	–167	11.1	3.59	57	–16.7	.146	20	.21	158	1.01
3.0	.46	178	9.5	2.97	45	–16.4	.152	16	.17	156	1.07
3.5	.48	173	7.9	2.49	33	–16.2	.155	11	.14	163	1.15
4.0	.48	164	6.6	2.13	22	–16.1	.156	9	.11	–175	1.27
4.5	.48	155	5.5	1.87	13	–15.9	.161	5	.11	–154	1.35
5.0	.48	143	4.5	1.67	3	–15.8	.163	3	.14	–141	1.46

Typical Performance, T_A = 25°C

(unless otherwise noted)

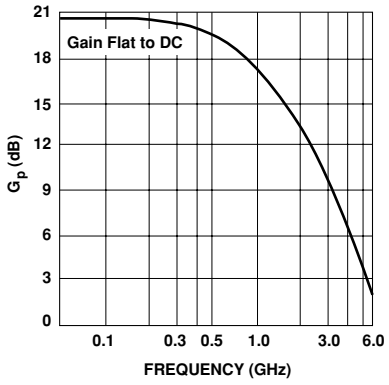


Figure 1. Typical Power Gain vs. Frequency, T_A = 25°C, I_d = 16 mA.

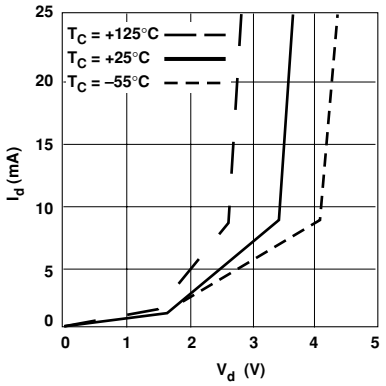


Figure 2. Device Current vs. Voltage.

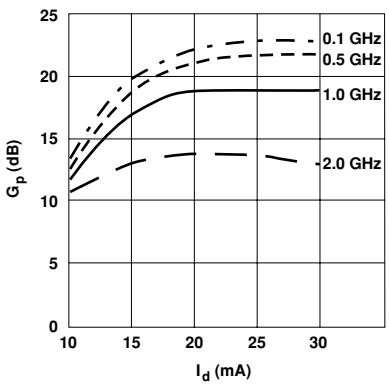


Figure 3. Power Gain vs. Current.

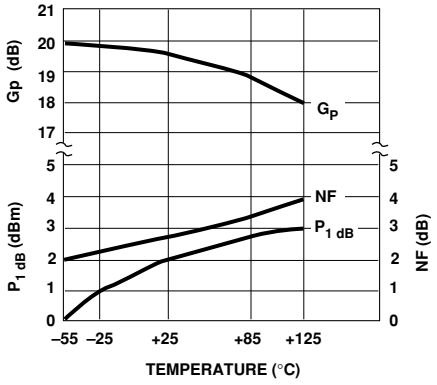


Figure 4. Output Power at 1 dB Gain Compression, NF and Power Gain vs. Case Temperature, f = 0.5 GHz, I_d = 16 mA.

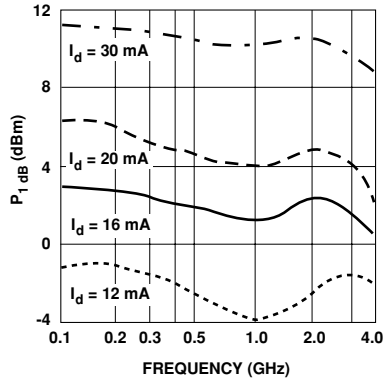


Figure 5. Output Power at 1 dB Gain Compression vs. Frequency.

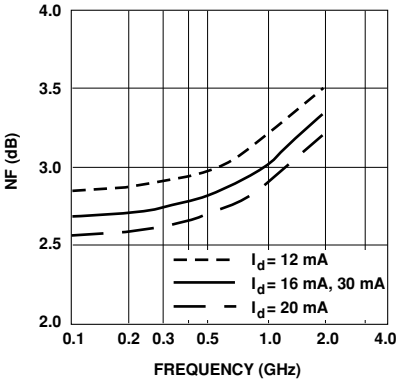
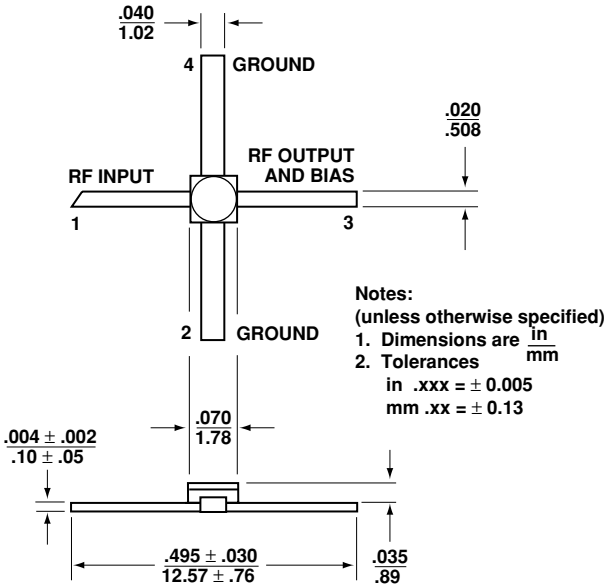


Figure 6. Noise Figure vs. Frequency.

Ordering Information

Part Numbers	No. of Devices	Comments
MSA-0670	10	Bulk

70 mil Package Dimensions



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Data subject to change.

Obsoletes 5966-4949E
April 4, 2005
5989-2763EN

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